

11th International Summer School on RF MEMS and RF Microsystems IHP, Frankfurt (Oder) – Germany June 22nd – 26th 2015

Basics of mm-wave Measurements

Dr. Andrej Rumiantsev

Director RF Technologies MPI Corporation

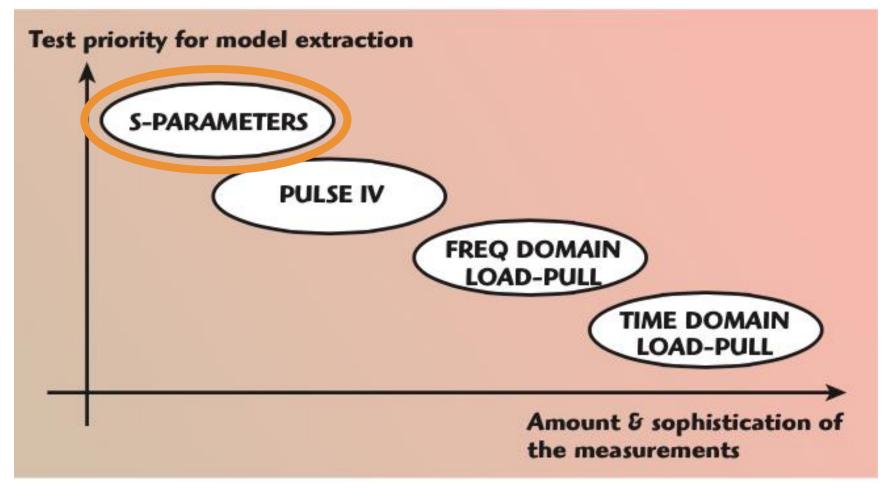


Outline

- Introduction
- S-parameters Basics
- Measurement of S-parameters
- VNA Building Blocks
- Instrumentation



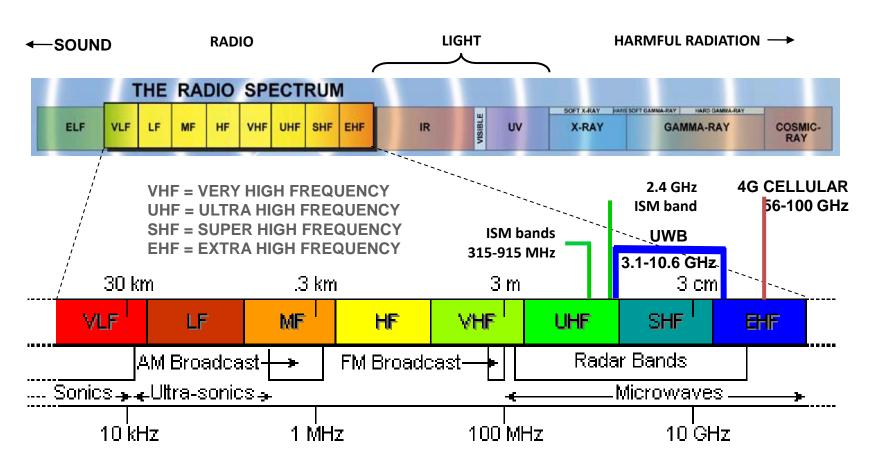
Importance of RF-Measurements



T. Gasseling, MW Journal, 03-2012



Where Do RF & Microwaves Start?



10 GHz ~ 3 cm wave length

Source: JSC.MIL

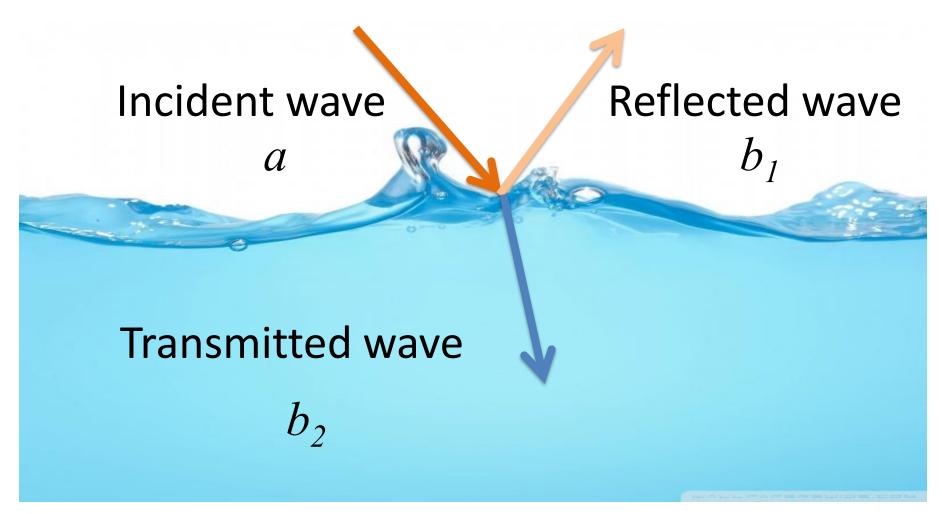


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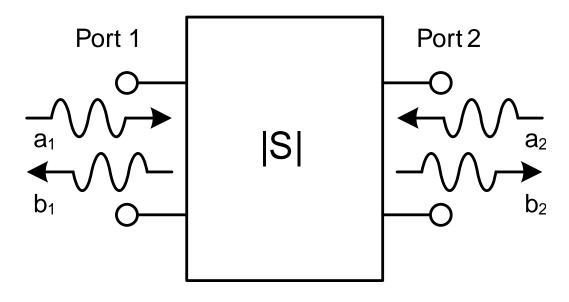
..its all about Waves





··· over S-Parameters

- Relationship of:
 - incident (a) and reflected/transmitted (b)
 waves at device terminals





Why S-Parameters

- Wave quantities are easy to measure
- Can be converted to *Z*-, *Y*-, *H* and other parameters

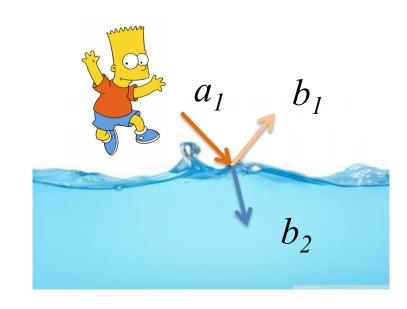
$$S_{ii} = \frac{b_i}{a_i} = \frac{Z_{DUT} - Z_{REF}}{Z_{DUT} + Z_{REF}}$$



S-Parameter Matrix

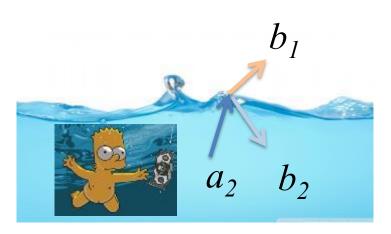
Forward direction

$$S_{11}=b_1/a_1$$
 $S_{21}=b_2/a_1$



Reverse direction

$$S_{22} = b_2/a_2$$
 $S_{12} = b_1/a_2$

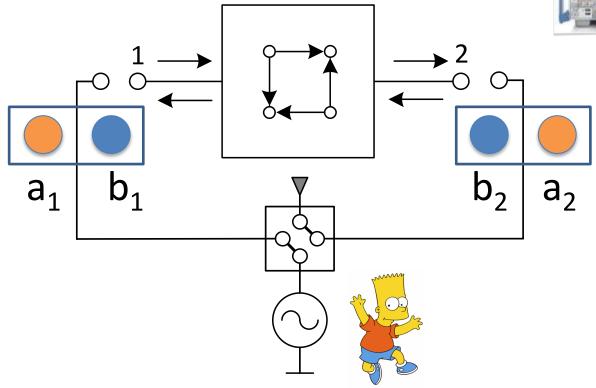




S-Parameters Measured by VNA

Vector Network Analyzer (VNA)

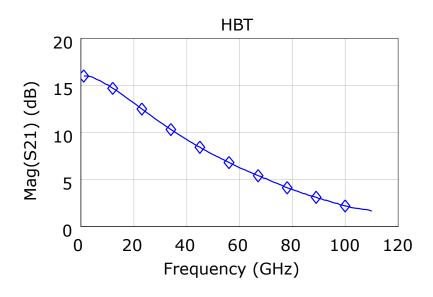


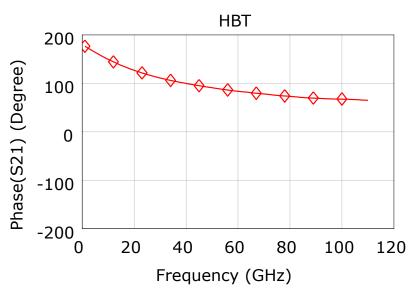




Why "Vector"?

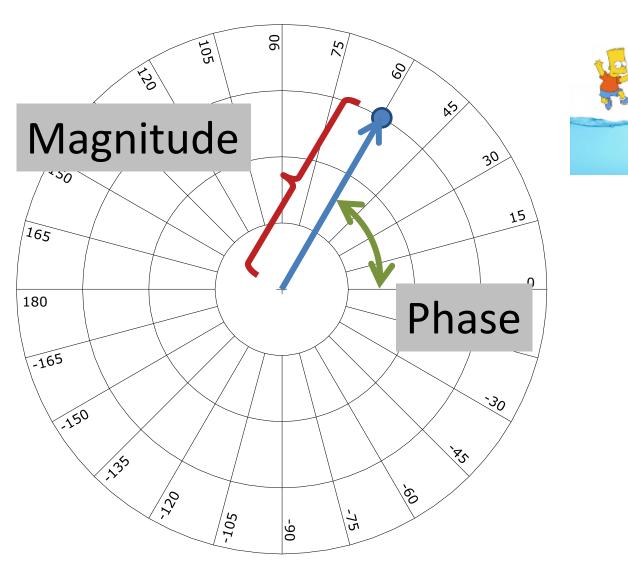
- S-parameters are complex quantities:
 - Magnitude
 - Phase





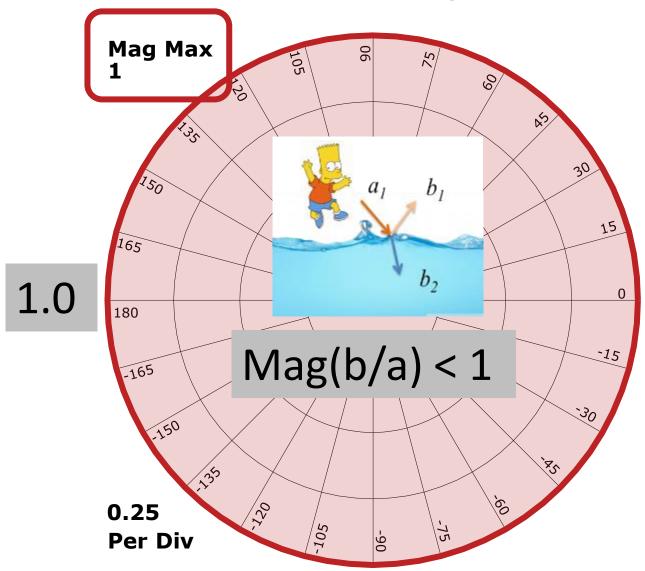


Vector on Polar Plot



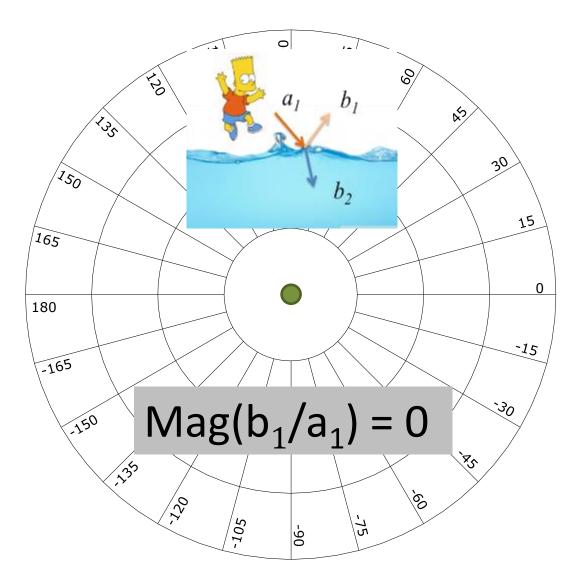


Passive Component



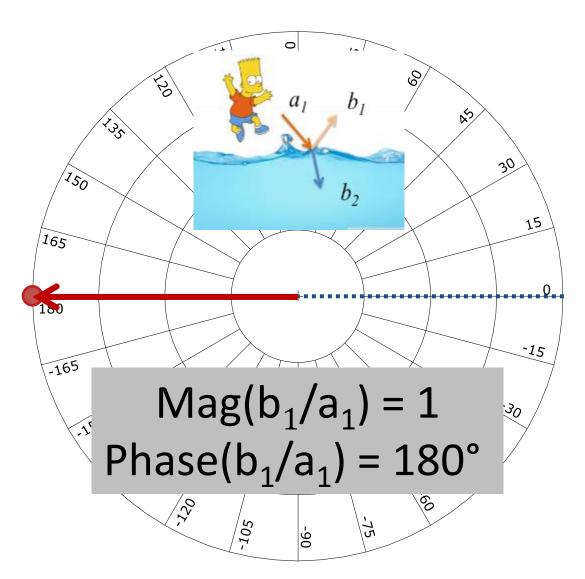


Match (Load)



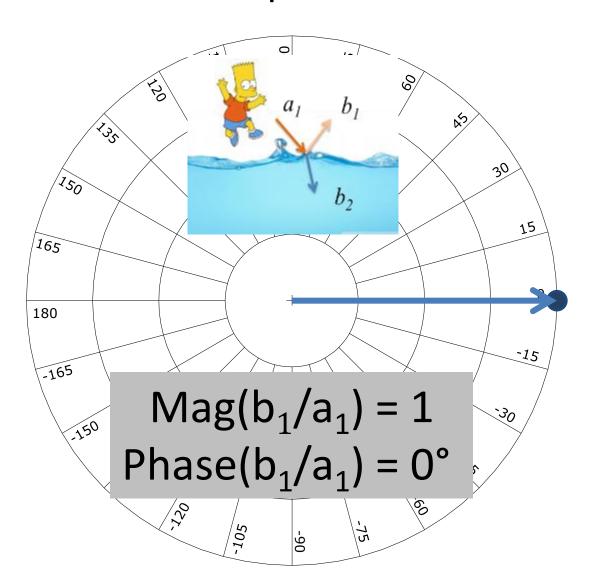


Short



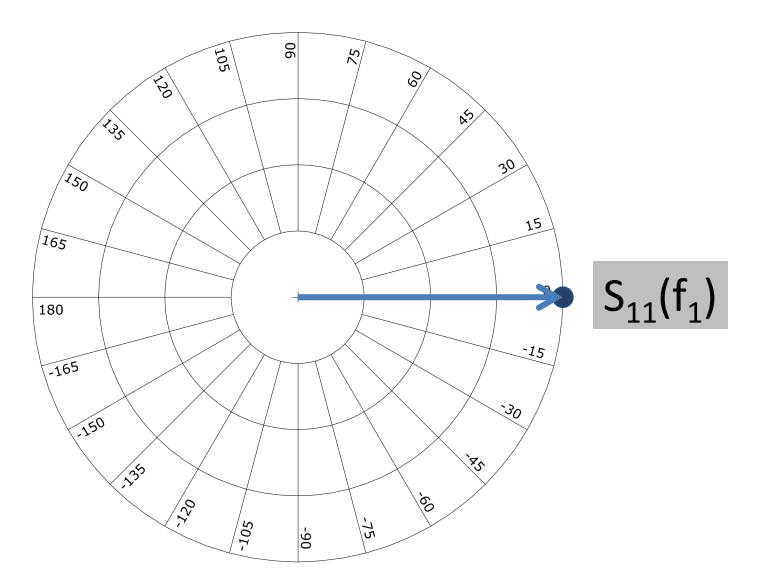


Open



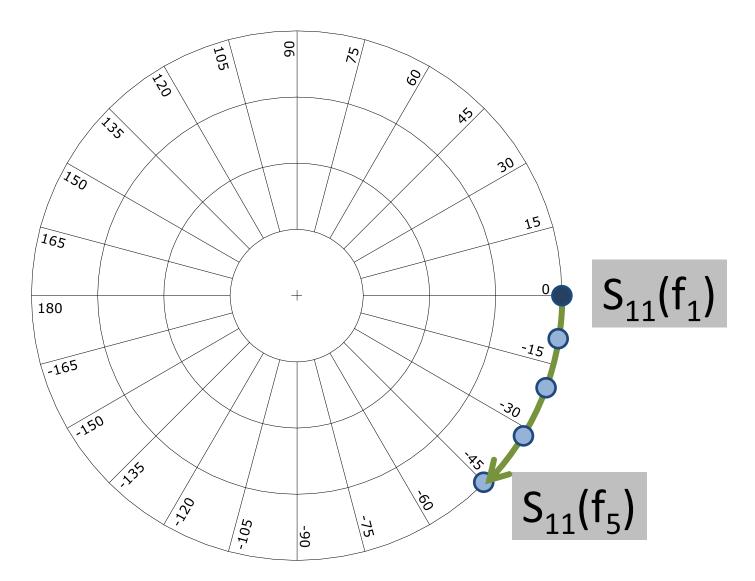


Data over Frequency



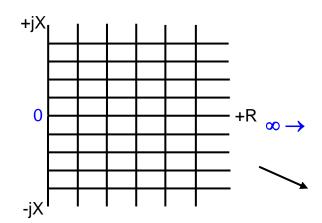


Data over Frequency



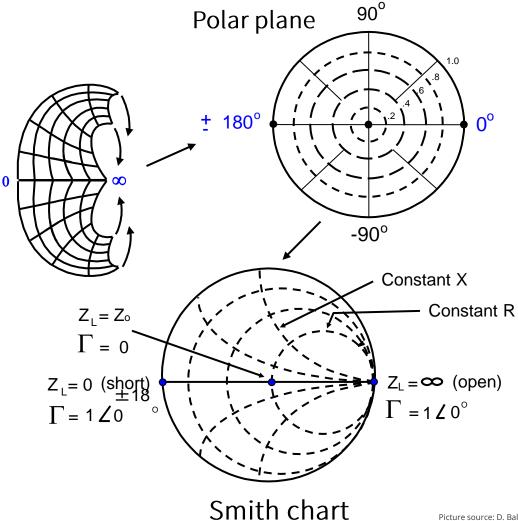


Smith Chart



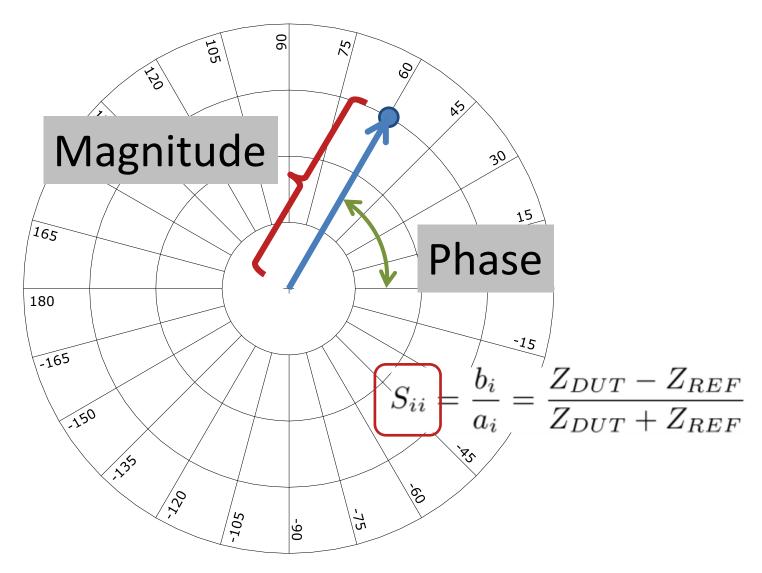
Rectilinear impedance plane

Smith Chart maps rectilinear impedance plane onto polar plane



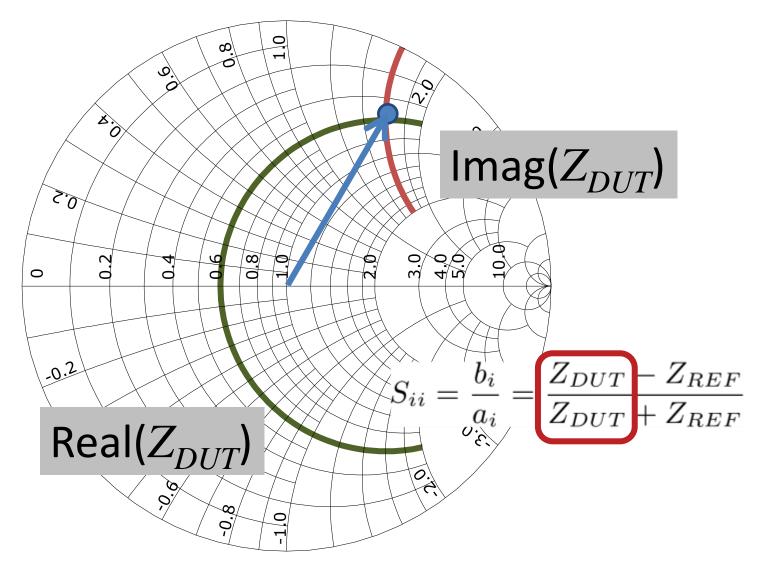


Polar Chart vs. Smith Chart





Polar Chart vs. Smith Chart





Matching of two Media = Transparency

 $Z_{0 (AIR)}$





Matching of two Media = Transparency





Matching of two Media = Transparency

 $Z_{0 (AIR)}$ Incident wave

Reflected wave $b_1 \rightarrow 0$

Transmitted wave

 $Z_{0 \text{ (WATER)}}$

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Matching Conditions

$$S_{ii} = \frac{b_i}{a_i} = \frac{Z_{DUT} - Z_{REF}}{Z_{DUT} + Z_{REF}}$$

$$b_1 \rightarrow 0$$

$$Z_{DUT} = Z_{REF}$$

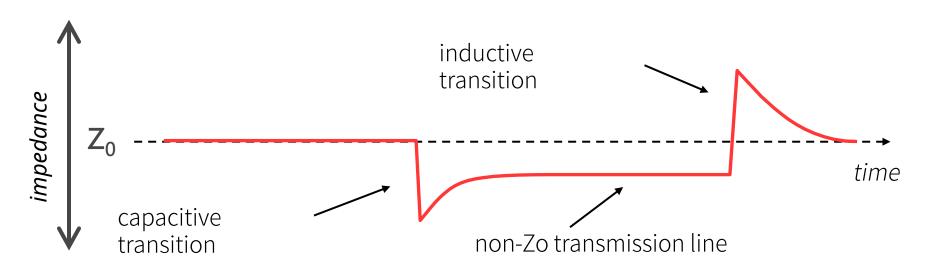
$$S_{ii} \rightarrow 0$$

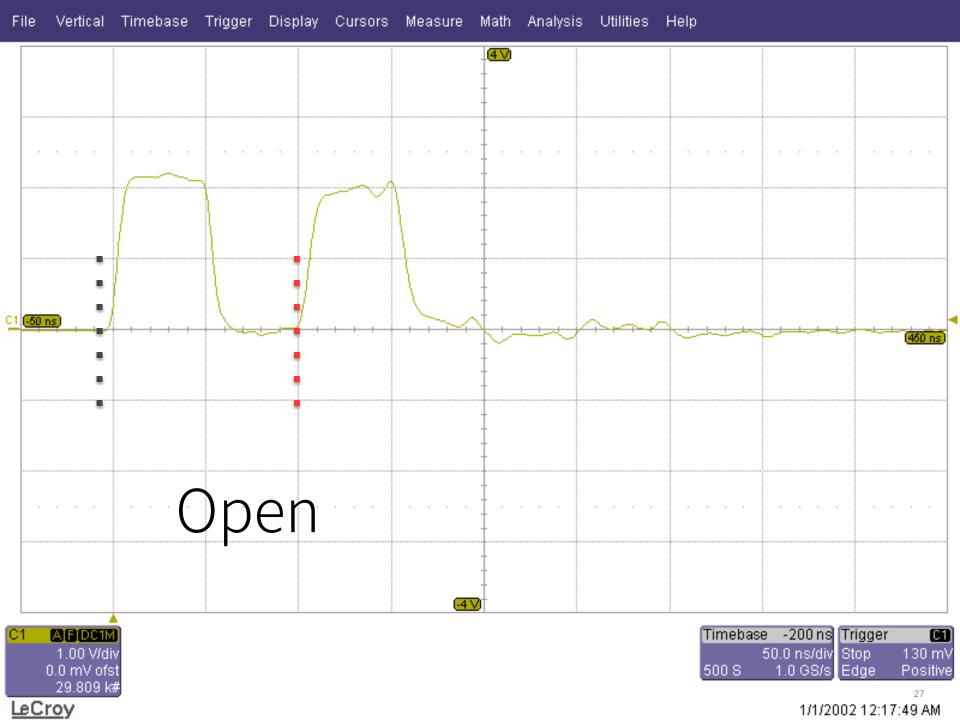
$$Z_{REF} = 50 \Omega$$

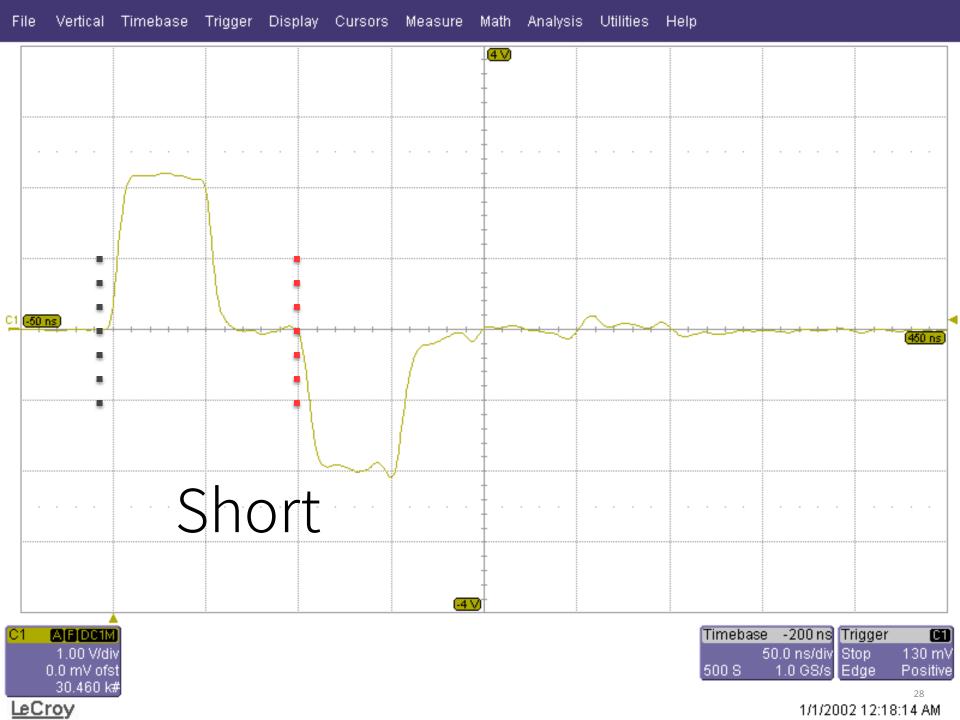


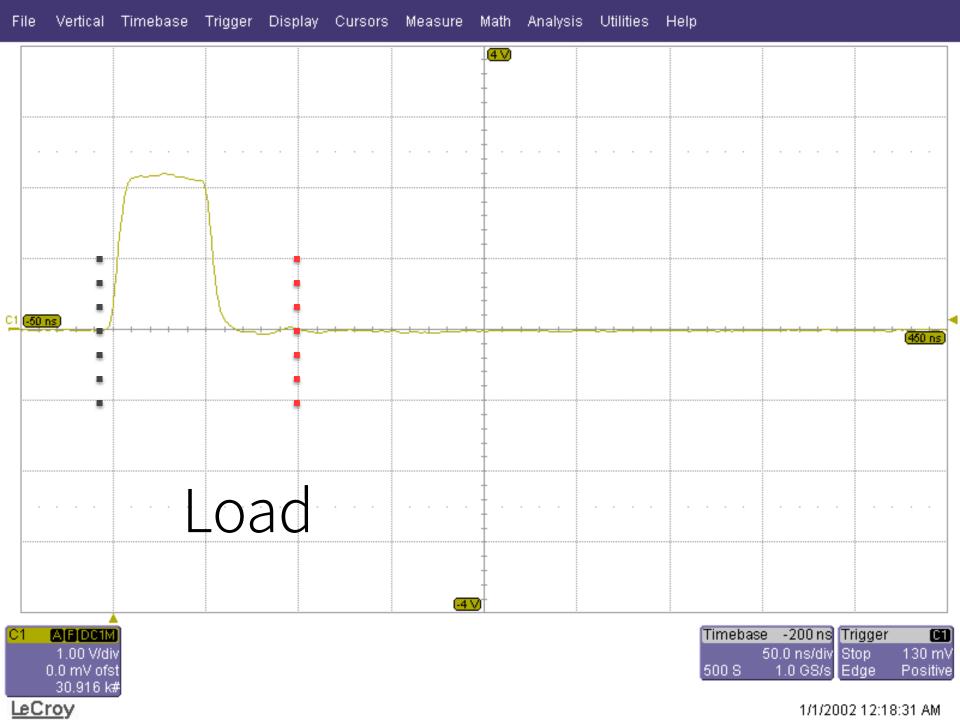
Time-Domain Reflectometry (TDR)

- Analyze impedance versus time
- Distinguish between inductive and capacitive transitions











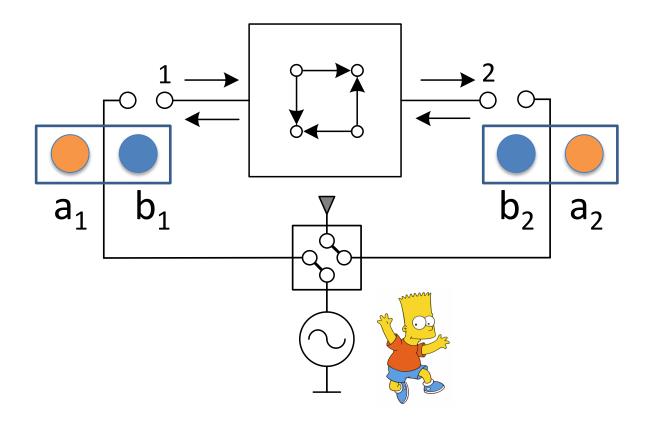
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Vector Network Analyzer

Device Under Test (DUT)





At the early days…



- Dr. Rohde and Dr. Schwarz first commercial product for RF measurement: 1933
- Z-g Graph from Rohde & Schwarz, early 50s



End of 60s...70s...80s...







Wiltron 310



R&S

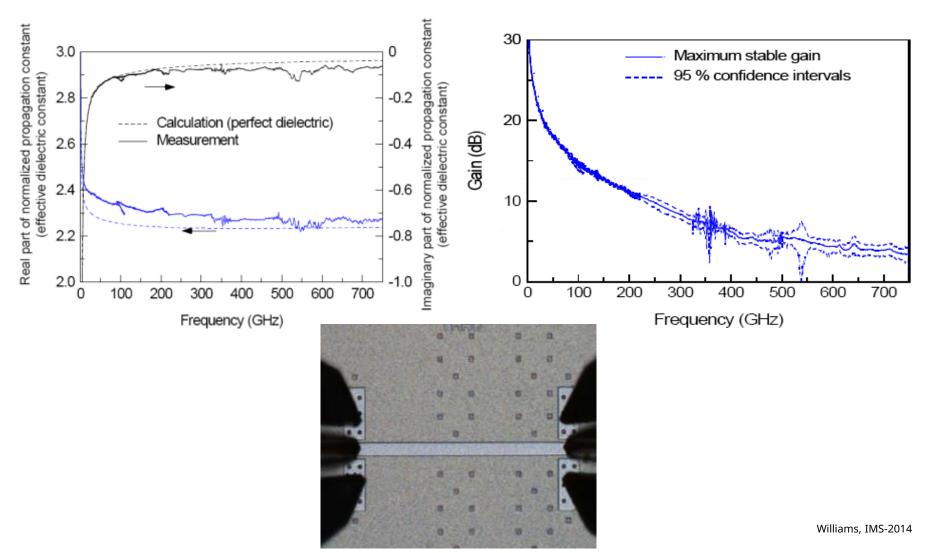


HP8410 Still Alive!





Today: On-Wafer Measurement



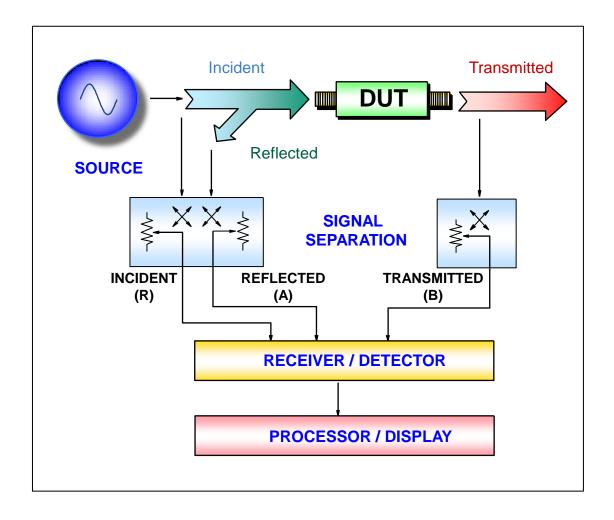


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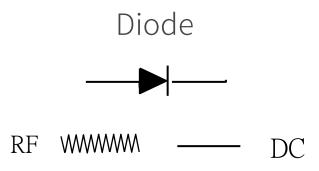


VNA Building Blocks

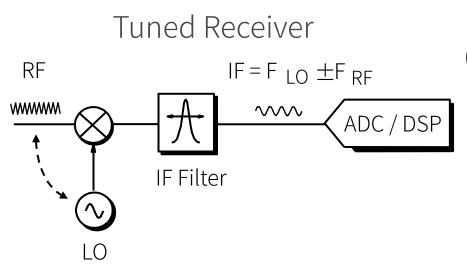




Receiver / Detectors



Scalar (no phase information)

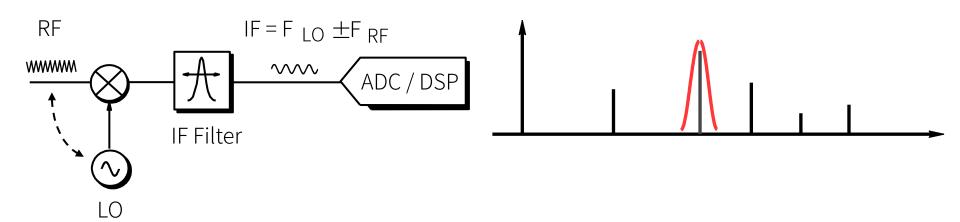


Vector (magnitude and phase)

38



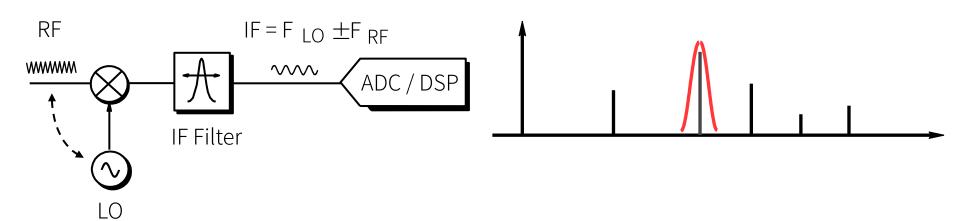
Narrowband Detection: Heterodyne Receiver



- Best sensitivity / dynamic range
- Provides harmonic / spurious signal rejection



Narrowband Detection: Heterodyne Receiver

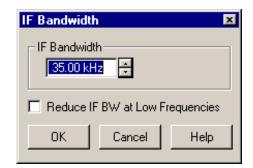


Trade off: noise floor and measurement speed



IF Bandwidth and Averaging

- Improve dynamic range by:
 - increasing power,
 - decreasing IF bandwidth, or
 - Averaging

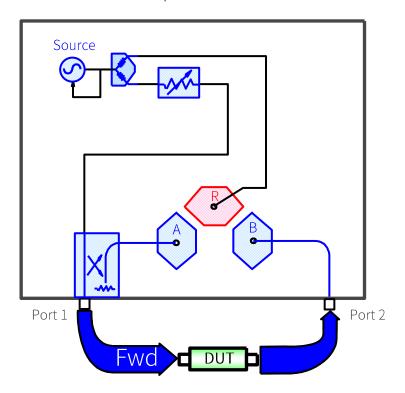


- Recommended IFBW value 100 Hz
- Averaging: OFF



T/R Versus S-Parameter Test Sets

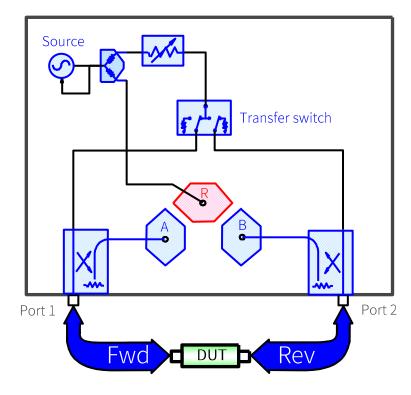
Transmission/Reflection Test Set



RF always comes out port 1 Port 2 is always receiver Response, one-port cal available

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S-Parameter Test Set



RF comes out port 1 or port 2 Forward and reverse measurements Two-port calibration possible

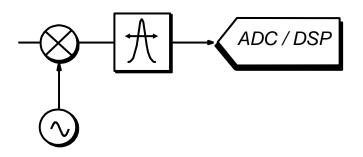
Picture source: D. Ballo Keysight

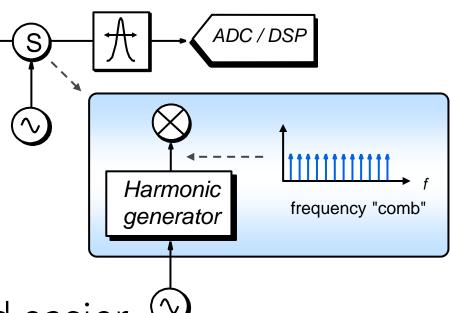


Front Ends: Mixers Versus Samplers

Mixer-based front end

Sampler-based front end



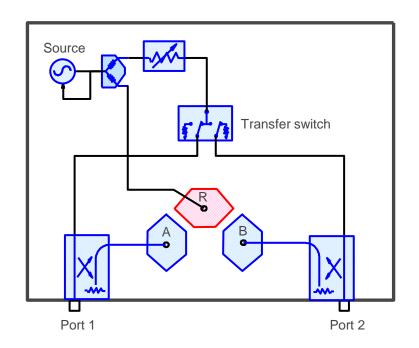


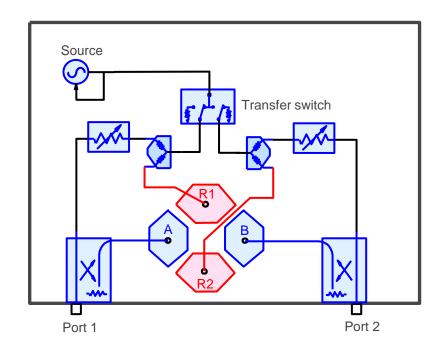
- Samplers: cheaper and easier
- Dynamic range?

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Three vs. Four-Receiver Analyzers





- Reference Channel
 - Economy
 - Up to 20 GHz

- Double-Reflectometer
 - High-end
 - Up to THz

Picture source: D. Ballo Keysight



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What do we have today?

Instruments











Frequency Extenders



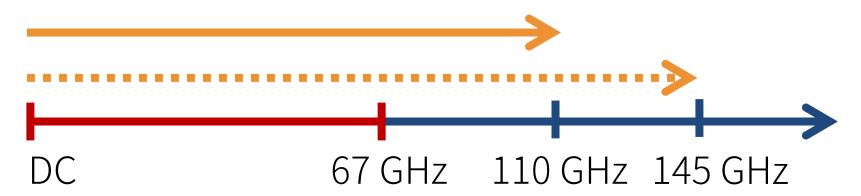






Frequency Range

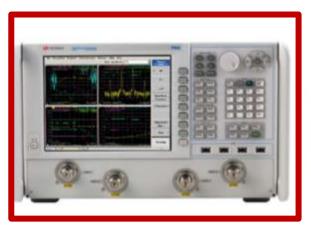
- Baseband unit
 - From few Hz to 67 GHz
- Frequency extenders
 - From 67 GHz to 1.1 THz
 - Single sweep: from DC to 110 GHz (145 GHz)





Keysight (former Agilent)











PNA-X

FiledFox PXI-VNA

ENA



PNA Family

4	Model		Typical application	Frequency range
	#0-5HH5-5H	N524xA PNA-X Series Most advanced and flexible VNA	 Replace an entire rack of equipment with one instrument Complete linear and nonlinear active device characterization 	 10 MHz to 8.5/13.5/26.5/ 43.5/50/67 GHz Up to 1.1 THz with extenders
PNA Family Reach for unrivaled excellence		N522xA PNA Series High performance microwave VNA	 Highest performance passive component analysis Active components characterization Metrology and cal lab 	 10 MHz to 13.5/26.5/ 43.5/50/67 GHz Up to 1.1 THz with extenders
		N523xA PNA-L Series Economy microwave VNA	 Microwave S-parameter test Signal integrity Material measurements 	 300 kHz to 8.5/13.5/20 GHz 10 MHz to 43.5/50 GHz



ENA Family

	Model		Typical application	Frequency range
ENA Drive down the cost of test		E5072A ENA High performance RF VNA with configurable test set	 RF amplifier test BTS components PIM measurements 	- 30 kHz to 4.5/8.5 GHz
		E5071C ENA High performance RF VNA	 RF component test Multiport module test Material measurements Signal integrity 	 9 kHz to 4.5/6.5/8.5 GHz 300 kHz to 14/20 GHz
		E5061B ENA LF-RF VNA with impedance analysis function Low cost RF VNA	 LF component/circuit test Component Z evaluation RF component test CATV component test 	 5 Hz to 3 GHz 100 kHz to 1.5/3 GHz
		E5063A ENA Low-cost RF VNA for passive component test	 Antenna manufacturing test RF passive component test Material measurements PCB manufacturing test 	- 100 kHz to 4.5/8.5/18 GHz







High-end: ZVA



Midrange: ZVB 40GHz



Economy: ZVD 8.5GHz



Portable: ZVL 13.5GHz



Incitsu envision: ensure







ShockLine: MS46xxx 40GHz



New Players



S5048 4.8GHz



P814 8.0GHz



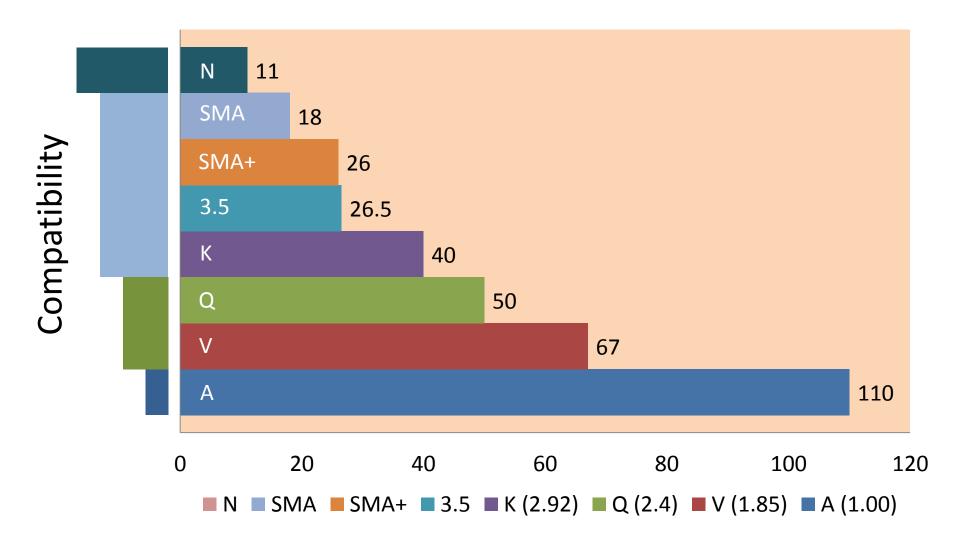




PXIe-5632. 8.5GHz



Frequency Limits and Compatibility



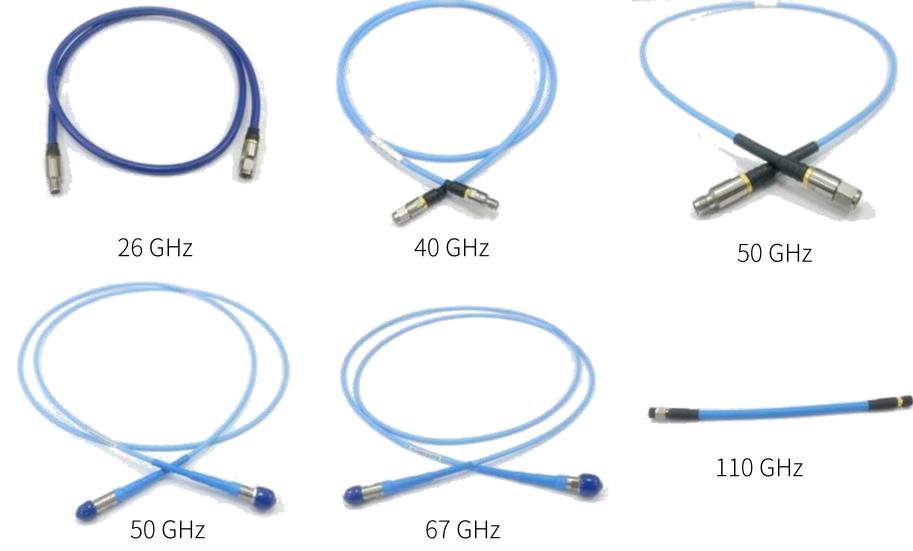


Cable and Connectors





Cables





Comparison



Entry-level



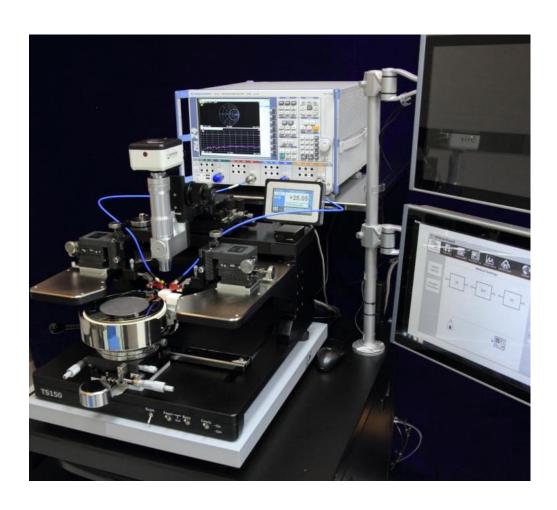


High-end





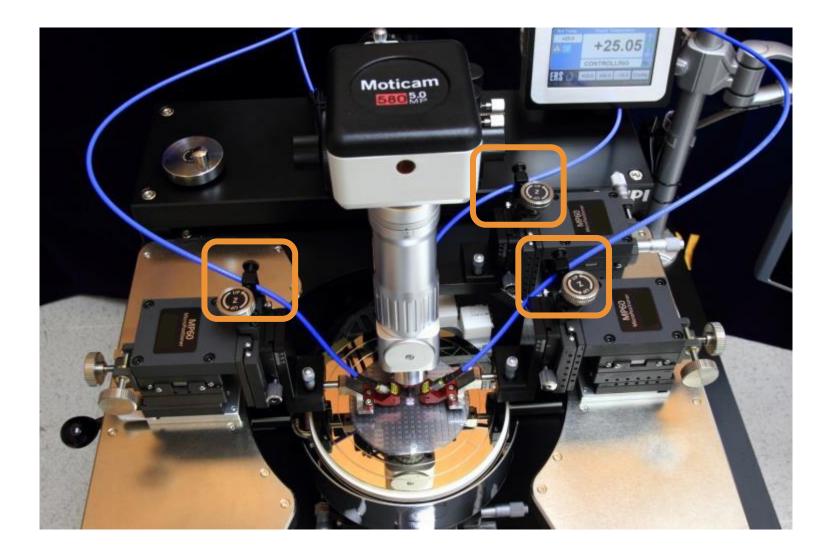
VNA Integration



- At the back
- Integrated shelf
- Optimized cable length: 80 cm



Cable Management on Positioner



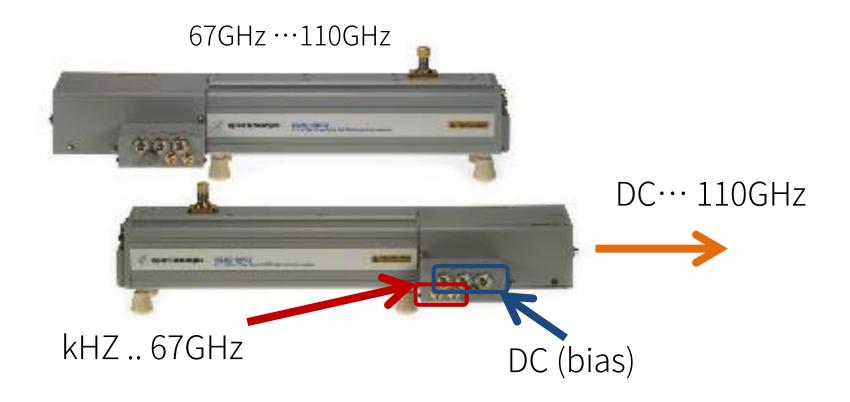


Beyond 67 GHz below 110 GHz

- External mm-wave heads ("extenders")
 - From 67 GHz to 110 GHz
- Combiners
 - DC (bias source)
 - kHz····67GHz (baseband VNA)
 - 67GHz..110GHz (extenders)
- Broadband S-parameter measurement system

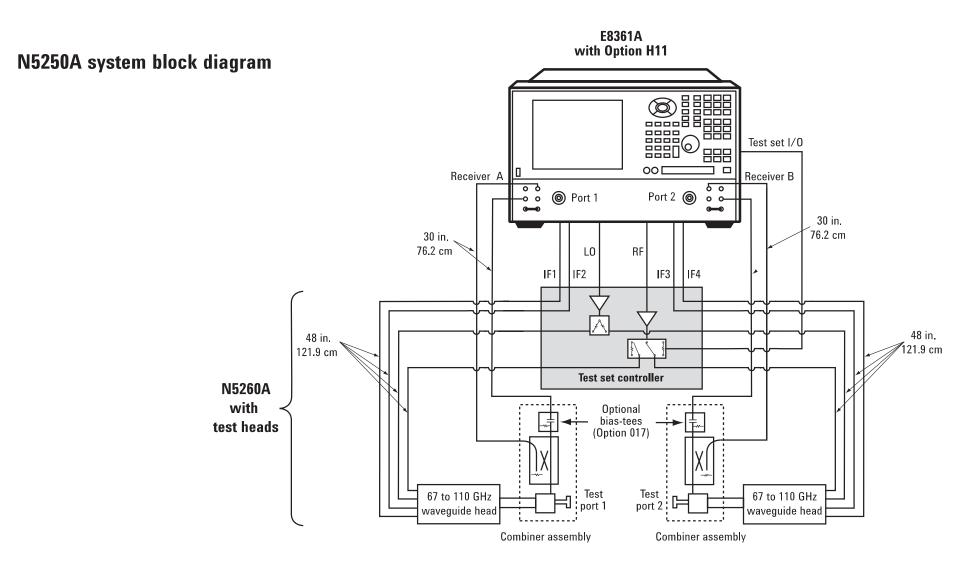


mm-Wave Heads



- IV/ S-Parameters measurements
- Device characterization for modeling







Broadband Systems





Key Wafer-Level Requirement

mm-wave heads close to the DUT









Banded Solutions

Band	WR15	WR12 ¹	WR10 ¹	WR08	WR06	WR05	WR03	WR02.2
Waveguide Interface								
Frequency (GHz)	50-75	60-90	75-110	90-140	110-170	140-220	220-325	325-500

- Dedicated mm-wave extender per band
- Our interest: from WR-10 and beyond



Banded Solutions: up to 1.1THz











Banded Solutions: up to 500GHz





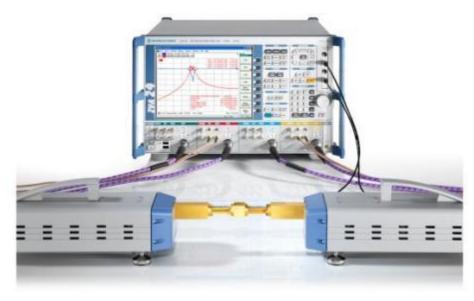




Banded Solutions: up to 500 GHz









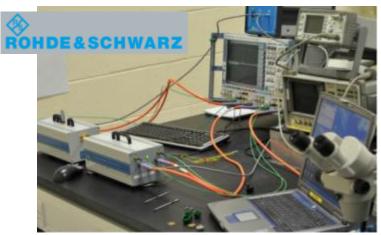


Banded Solutions: up to 325 GHz



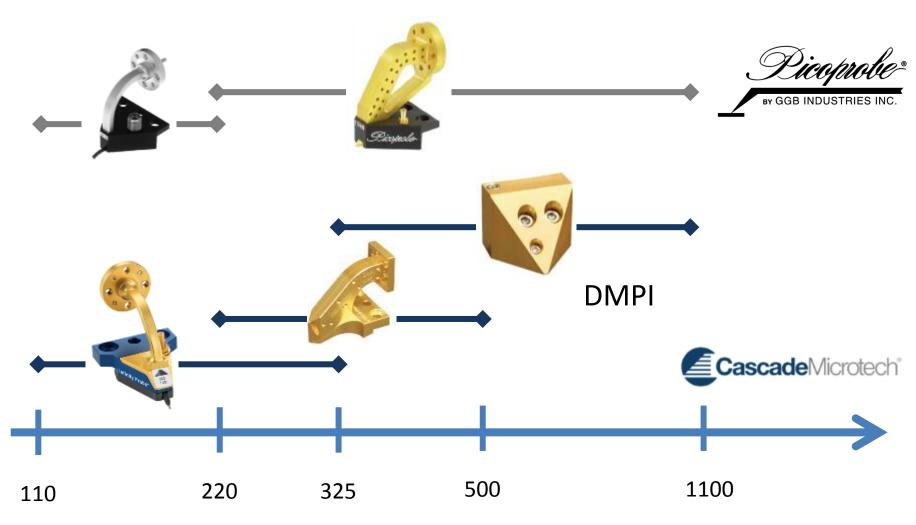






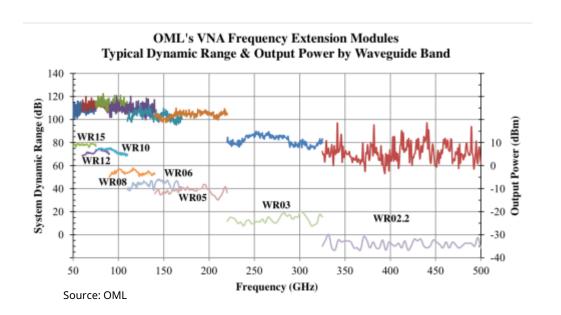


Banded Probes

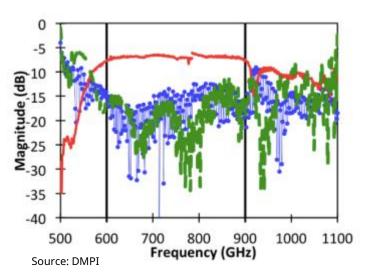




Banded Measurement Challenges



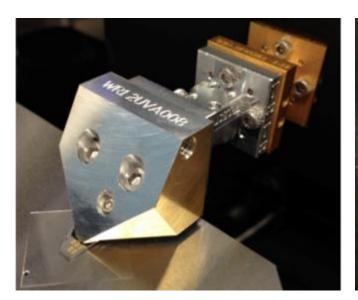
DMPI 1.1 THz Probe

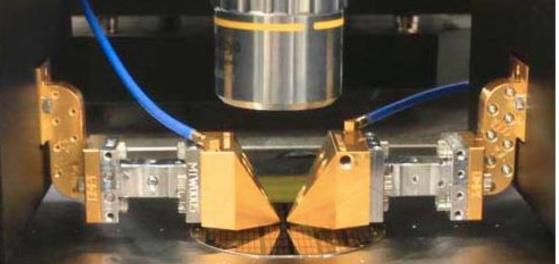


- VNA dynamic range decreases
- Waveguide losses increases
- Probe performance degrades



Probe Integration





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Dedicated TS150-THZ System





READY FOR THE TESTTM

MPI T5 150-THZ 150 mm Manual Probe System

Industry's first explicitly designed probe system for accurate mmW and THz measurements

Microscope Mount and Movement

- Stable bridge for high quality optics
- 90° tilt for easy reconfiguration
- 50 x 50 mm linear XY movement

4-Port Bridge

- Two: in North and South
- Rectangular adjustments for RF positioners
- Designed as standard feature for DC biasing or 4-port RF
- For single DC or RF MicroPositioners

MicroPositioners

- Unique over-travel control option
- MP80-DX option for accurate multi-line TRL calibration
- Supports max. 2 bold down large area MP80 MicroPositioners

Probe Platen

- · Single large probe platen in rigid design
- 4 probe platen supports for max. stability
- Designed especially to accommodate large positioners for mmW and THz applications

Unique Platen Lift

- Three discrete positions for contact, separation (300 µm) and safety loading 3 mm
- · Safety lock function at loading position
- "Auto Contact" position with ±1 µm repeatability for consistent contact quality

- Designed for bench top use
- Comes with vibration absorber base
- Low profile design for maximum usability
- Ideal for mmW, THz and load pull applications

Front Mounted Vacuum Control

- Easy access
- Clearly marked

Ausilable Ontions

- · Various adaptations for different · Table with integrated rack for thermal controller,
- frequency extenders · Vibration isolation table
- computer and keyboard push tray
- Dual monitor stand option
- Instrument shelf option

Microscope and Optics Options

- Various optics options available
- Single tube MPI SZ10, MZ12 with up to 12x zoom and 95 mm working distance
- HDMI cameras, monitor user interface without computer

Modular Chucks

- · Non-thermal or hot only chucks
- Dedicated RF or mmW designs
- Field upgradable for reduced cost of ownership
- Easy switch between center and small wafer size control

- 2 auxiliary chucks for calibration substrates
- Built-in ceramic for accurate calibration
- 1 µm flatness for consistent contact quality

MP80 Integration Modules

- 2 options for waveguide or coax application
- Universal large area platforms for integrating various frequency extenders up to 1.1 THz
- Micrometer screws for fine waveguide probe leveling on the platforms
- Dove-tail interface for dedicated adaptations for easy setup and switching between different frequency bands

Chuck XYZ Stage Movement

- . Unique puck controlled air bearing stage for quick single-handed operation
- Large vacuum base for max, stability
- 180 x 300 mm XY total stage movement
- Resolution < 1.0 μm (0.04 mils) @ 500 μm/rev
- 25 x 25 mm micrometer fine XY adjustment
- 10 mm fine Z, resolution < 1.0 μm (0.04 mils) @ 500 μm/ rev, with digital indicator
- ±5° Theta fine adjustment
- Extra wide Y-range for easy loading

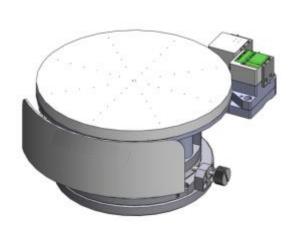
FACT SHEET - TS150-THZ v2.1, 07-2017 ◆ MPI Corporation 2017 - Data subject to change without further notion.



Designed for unsurpassed stability

- Large area stainless steel probe platen
- Probe platen at lowest possible position
- No chuck elevation

Ceramic chuck and AUX chucks



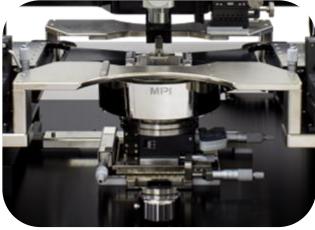




Dedicated Design for THz Application

- Support R&S and all other extenders:
 - up to 1.1THz
- 4-Port as part of the base system
- Fine 7 chuck

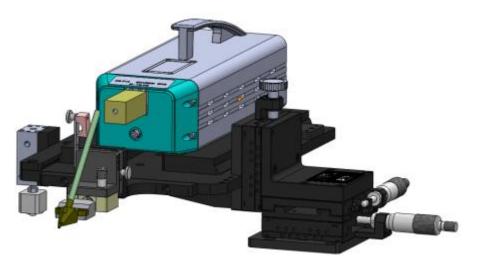


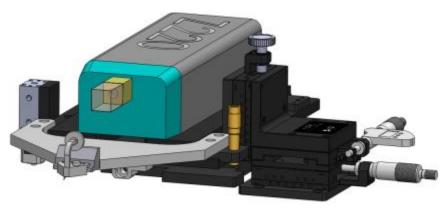






Different Extenders – Easy Reconfiguration



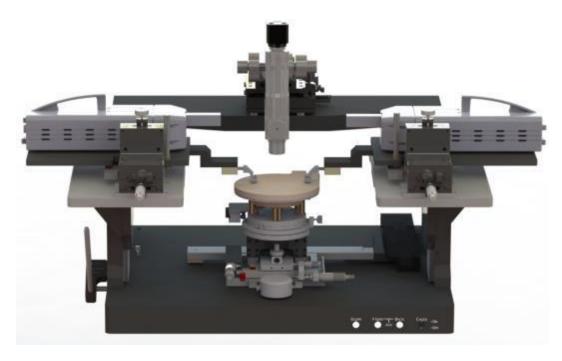


WR15, WR12, WR10

WR8



Banded 110 GHz…220 GHz

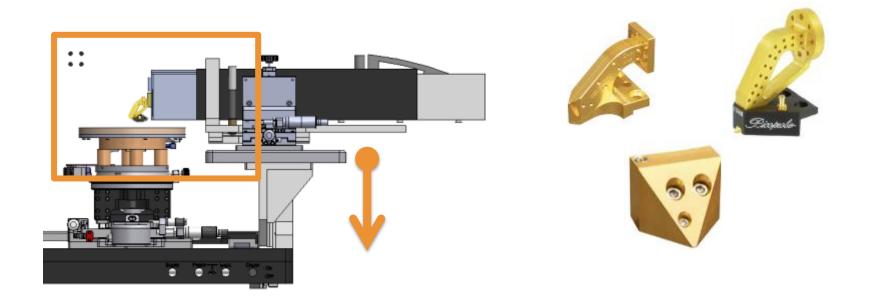




- Waveguide sections
 - Losses in are less critical
 - Probe performance is good



Banded THz Systems: 325+ GHz



- Losses and probe performance are critical
 - Direct probe mount
 - Unique low-down probe platen mechanism



THANK YOU FOR YOUR ATTENTION

For more information, please visit: www.mpi-corporation.com